

**Features:**

- n Isolated mounting base 3000V~
- n Pressure contact technology with Increased power cycling capability
- n Space and weight saving

**Typical Applications**

- n Various rectifiers
- n DC supply for PWM inverter

$V_{RRM}$	Type & Outline
2000V	MD400-20-417F2
2200V	MD400-22-417F2
2500V	MD400-25-417F2

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	$T_J(^{\circ}C)$	VALUE			UNIT
				Min	Type	Max	
$I_{F(AV)}$	Mean forward current	180° half sine wave 50Hz Single side cooled, $T_C=100^{\circ}C$	150			400	A
$I_{F(RMS)}$	RMS forward current					628	A
$I_{RRM}$	Repetitive peak current	at $V_{RRM}$	150			30	mA
$I_{FSM}$	Surge forward current	$V_R=60\%V_{RRM}$ , t=10ms half sine	150			13.0	kA
$I^2t$	$I^2t$ for fusing coordination					845	$10^3A^2s$
$V_{FO}$	Threshold voltage		150			0.85	V
$r_F$	Forward slope resistance					0.49	m $\Omega$
$V_{FM}$	Peak forward voltage	$I_{FM}=1200A$	25			1.44	V
$R_{th(j-c)}$	Thermal resistance Junction to case	Single side cooled per chip				0.09	$^{\circ}C/W$
$R_{th(c-h)}$	Thermal resistance case to heatsink	Single side cooled per chip				0.04	$^{\circ}C/W$
$V_{iso}$	Isolation voltage	50Hz, R.M.S, t=1min, $I_{iso}:1mA(MAX)$		3000			V
$F_m$	Terminal connection torque(M10)			10		12	N·m
	Mounting torque(M6)			4.5		6.0	N·m
$T_{vj}$	Junction temperature			-40		150	$^{\circ}C$
$T_{stg}$	Stored temperature			-40		125	$^{\circ}C$
$W_t$	Weight					770	g
<b>Outline</b>	417F2						

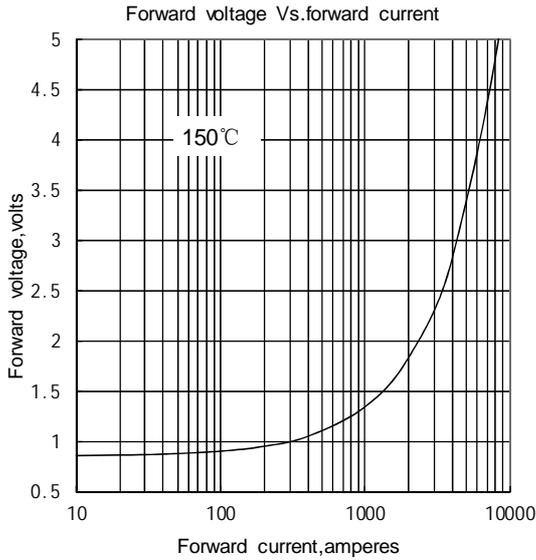


Fig.1

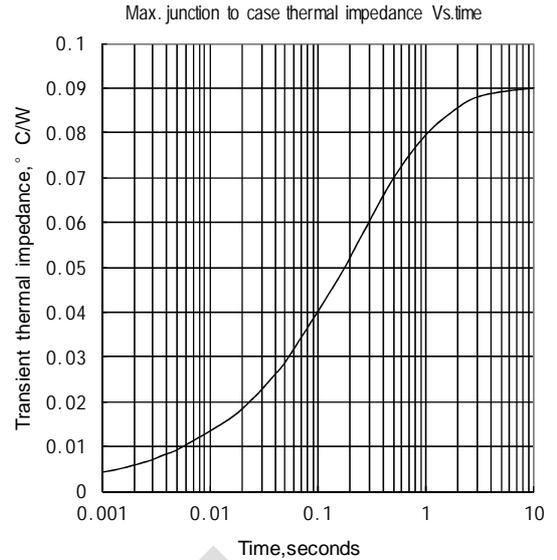


Fig.2

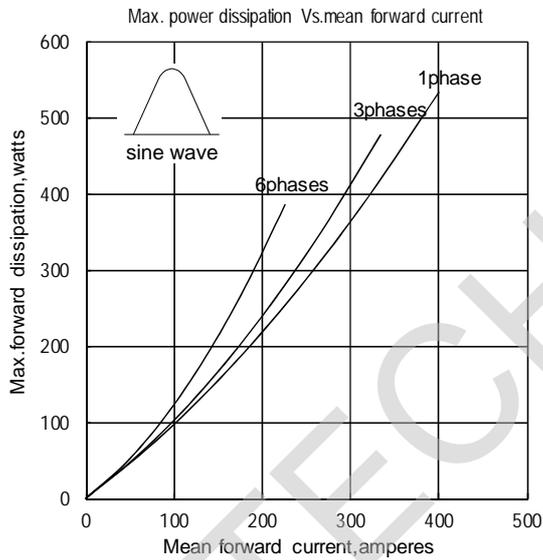


Fig.3

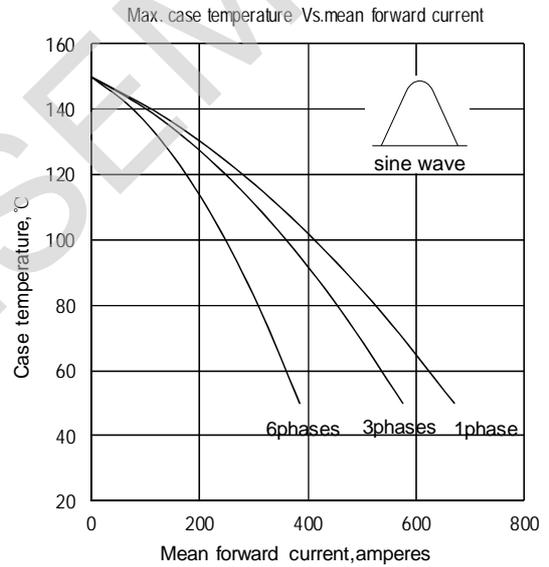


Fig.4

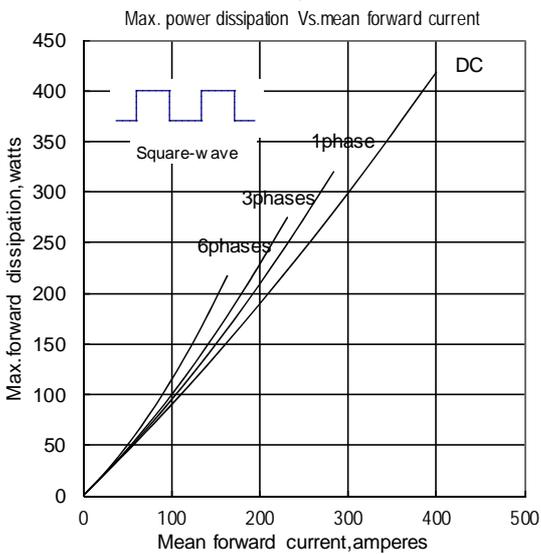


Fig.5

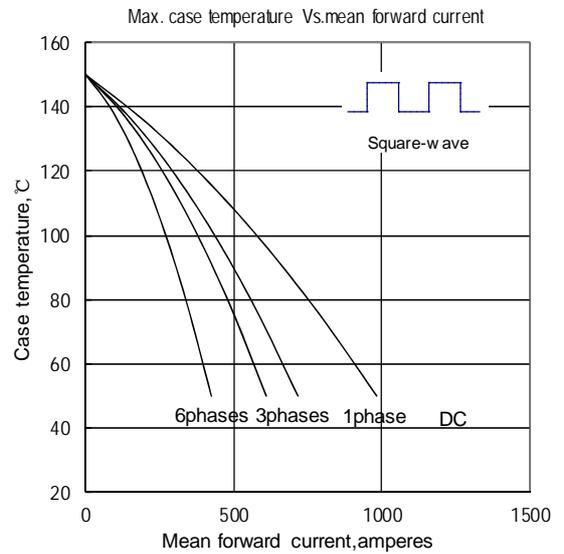


Fig.6

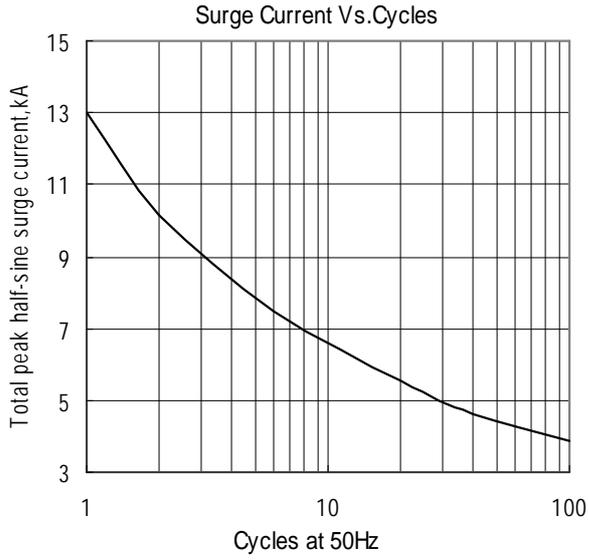


Fig.7

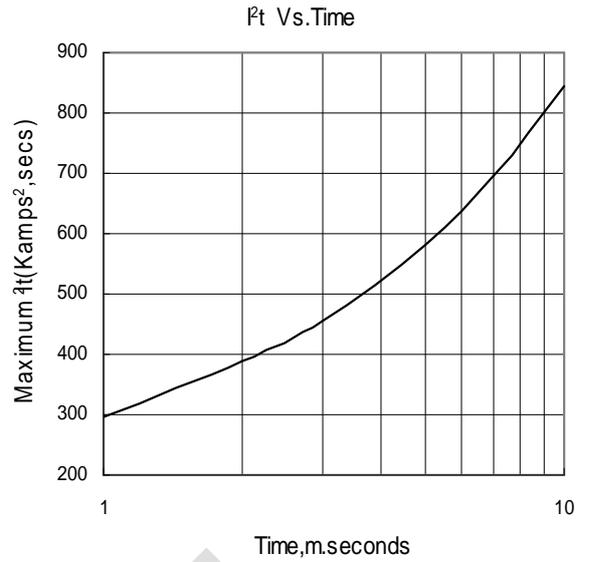
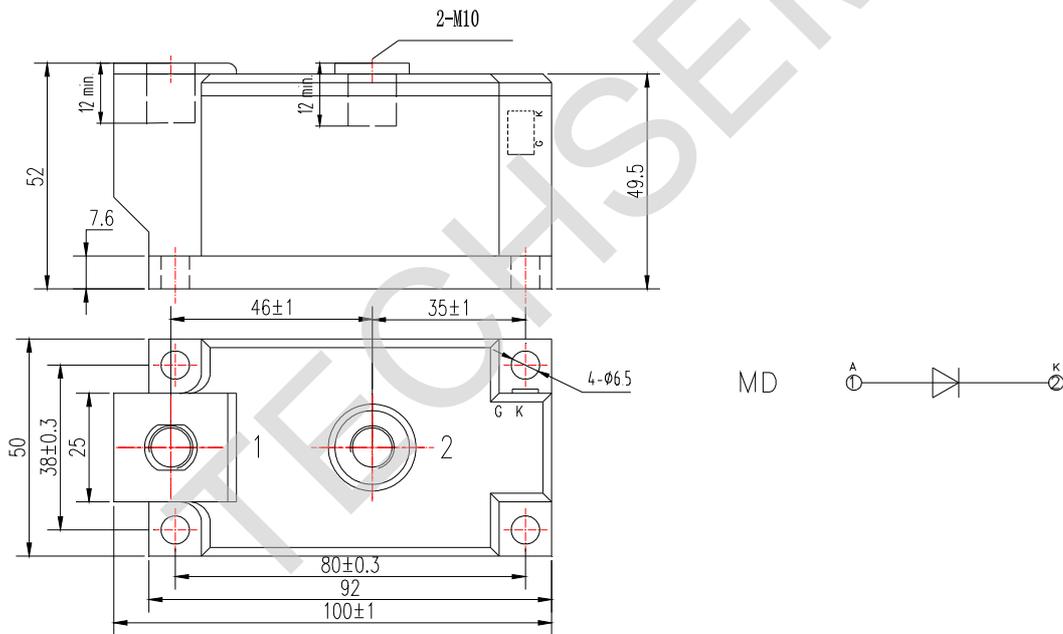


Fig.8

**Outline:**



Unmarked dimensional tolerance: ±0.5mm